

74LVX125

Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVX125 contains four independent non-inverting buffers with 3-STATE outputs. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

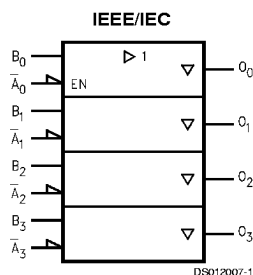
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Available in SOIC JEDEC, SOIC EIAJ and TSSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

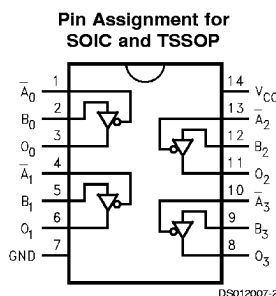
Order Number	Package Number	Package Description
74LVX125M	M14A	14-Lead (0.150" Wide) Molded Small Outline Package SOIC JEDEC
74LVX125SJ	M14D	14-Lead Molded Small Outline Package SOIC EIAJ
74LVX125MTC	MTC14	14-Lead Thin Shrink Small Outline Package TSSOP

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\bar{A}_n, B_n$	Inputs
O_n	Outputs

Truth Table

Inputs		Output
$\bar{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
X = Immaterial

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Diode Current (I_{IK}) $V_I = -0.5V$	-20 mA
DC Input Voltage (V_I)	-0.5V to +7.0V
DC Output Diode Current (I_{OK}) $V_O = 0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
Output Voltage (V_O)	-0.5V to $V_{CC} + 0.5V$
DC Output Source/Sink Current (I_O)	± 25 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	± 50 mA
Storage Temp. Range (T_{STG})	-65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$			$T_A = -40^\circ C$ to $+85^\circ C$		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	High Level Input Voltage	2.0	1.5			1.5		V		
		3.0	2.0			2.0				
		3.6	2.4			2.4				
V_{IL}	Low Level Input Voltage	2.0			0.5		0.5	V		
		3.0			0.8		0.8			
		3.6			0.8		0.8			
V_{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	$V_{IN}=V_{IL}$ or V_{IH}	$I_{OH}=-50 \mu A$
		3.0	2.9	3.0		2.9				$I_{OH}=-50 \mu A$
		3.0	2.58			2.48				$I_{OH}=-4 mA$
V_{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	$V_{IN}=V_{IL}$ or V_{IH}	$I_{OL}=50 \mu A$
		3.0		0.0	0.1		0.1			$I_{OL}=50 \mu A$
		3.0			0.36		0.44			$I_{OL}=4 mA$
I_{OZ}	3-STATE Output Off-State Current	3.6			± 0.25		± 2.5	μA	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND	
I_{IN}	Input Leakage Current	3.6			± 0.1		± 1.0	μA	$V_{IN} = 5.5V$ or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	$V_{IN} = V_{CC}$ or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ C$		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	-0.3	-0.8	V	50
V_{IHD}	Minimum High Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: Input $t_r = t_f = 3$ ns

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = +25° C			T _A = -40° C to +85° C		Units	Conditions
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay Time	2.7		5.8	10.1	1.0	13.5	ns	C _L = 15 pF
t _{PHL}	Data to Output			8.3	13.6	1.0	17.0		C _L = 50 pF
		3.3 ±0.3		4.4	6.2	1.0	8.5		C _L = 15 pF
				6.9	9.7	1.0	12.0		C _L = 50 pF
t _{PZH}	Output Enable Time	2.7		5.3	9.3	1.0	12.5	ns	C _L = 15 pF, R _L = 1 kΩ
t _{PZL}				7.8	12.8	1.0	16.0		C _L = 50 pF, R _L = 1 kΩ
		3.3 ±0.3		4.0	5.6	1.0	7.5		C _L = 15 pF, R _L = 1 kΩ
				6.5	9.1	1.0	11.0		C _L = 50 pF, R _L = 1 kΩ
t _{PHZ}	Output Disable	2.7		10.0	15.7	1.0	19.0	ns	C _L = 50 pF, R _L = 1 kΩ
t _{PLZ}	Time	3.3 ±0.3		8.3	11.2	1.0	13.0		C _L = 50 pF, R _L = 1 kΩ
t _{OSSL}	Output to Output	2.7			1.5		1.5	ns	C _L = 50 pF
t _{OSLH}	Skew (Note 4)								

Note 4: Parameter guaranteed by design. t_{OSSL} = |t_{PLHm} - t_{PLHn}|, t_{OSLH} = |t_{PHLm} - t_{PHLn}|

Capacitance

Symbol	Parameter	T _A = 25° C			T _A = -40° C to +85° C		Units
		Min	Typ	Max	Min	Max	
C _{IN}	Input Capacitance		4.0	10		10	pF
C _{PD}	Power Dissipation Capacitance (Note 5)		14				pF

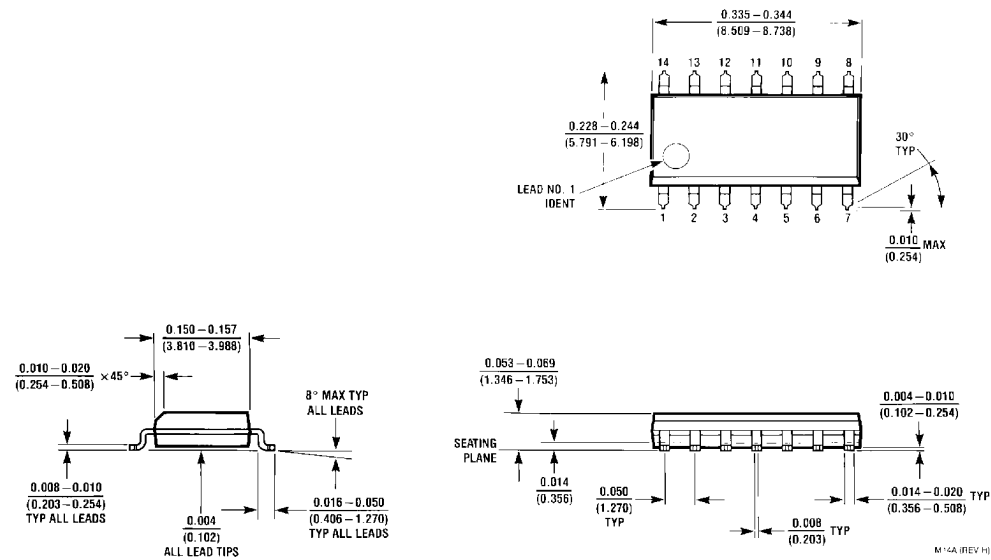
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

$$\text{Average operating current can be obtained by the equation: } I_{CC(\text{opr.})} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{4 \text{ (per bit)}}$$

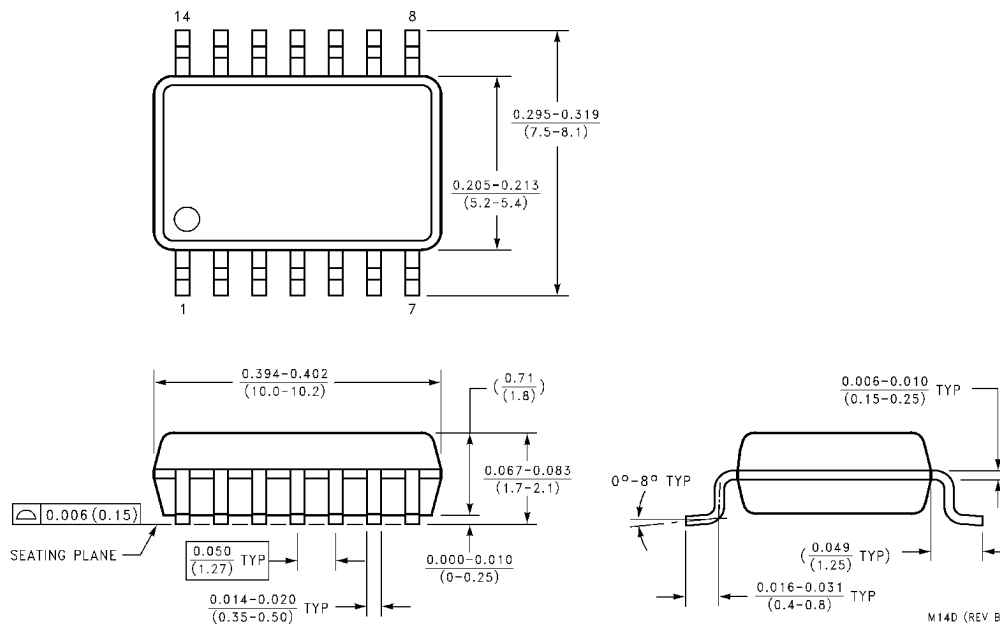
DS012007-4



Physical Dimensions inches (millimeters) unless otherwise noted

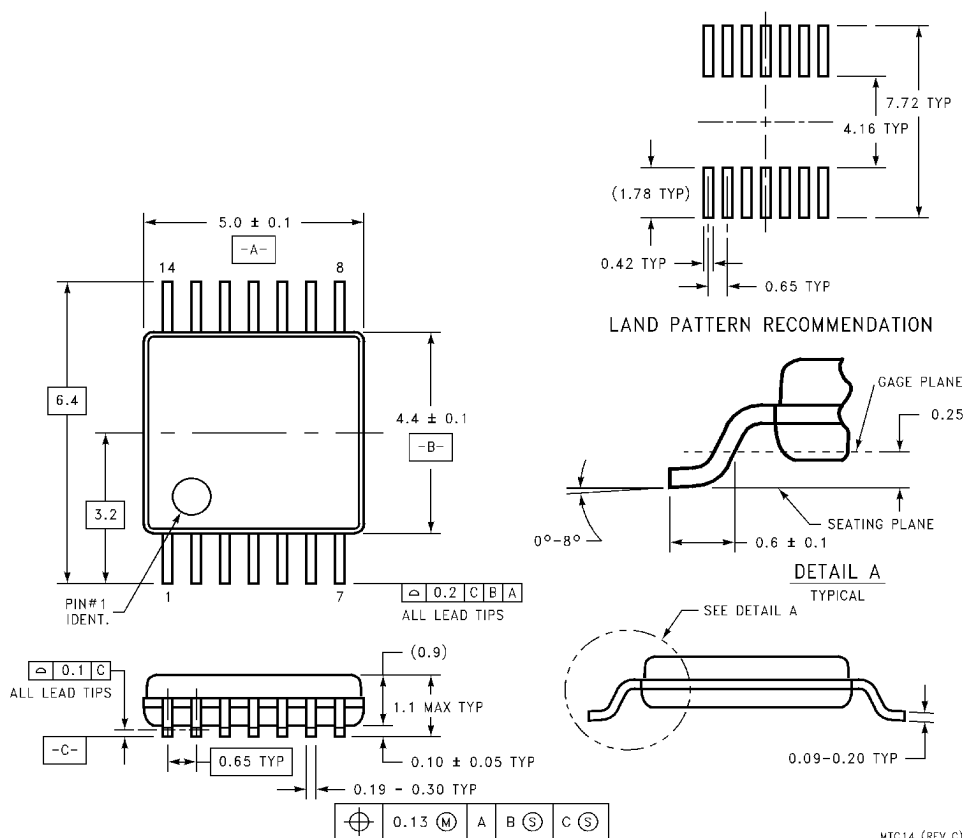


**14-Lead (0.50" Wide) Molded Small Outline Package, JEDEC
Package Number M14A**



**14-Lead Molded Small Outline Package, EIAJ
Package Number M14D**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Fairchild Semiconductor
Corporation
Americas
Customer Response Center
Tel: 1-888-522-5372

www.fairchildsemi.com

Fairchild Semiconductor
Europe
Fax: +49 (0) 1 80-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 8 141-35-0
English Tel: +44 (0) 1 793-85-68-56
Italy Tel: +39 (0) 2 57 5631

Fairchild Semiconductor
Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: +852 2737-7200
Fax: +852 2314-0061

National Semiconductor
Japan Ltd.
Tel: 81-3-5620-6175
Fax: 81-3-5620-6179

Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.